HD74HC679

12-bit Address Comparator

REJ03D0640-0200
(Previous ADE-205-526)
Rev.2.00
Mar 30, 2006

Description

The HD74HC679 address comparator simplifies addressing of memory boards and/or other peripheral devices. The four P inputs are normally hard wired with a preprogrammed address. An internal decoder determines what input information applied to the 12 A inputs must be low or high to cause a low state at the output (Y). For example, a positive-logic bit combination of 0111 (decimal 7) at the P input determines that inputs A_1 through A_7 must be low and that inputs A_8 through A_{12} must be high to cause the output to go low. Equality of the address amplified at the A inputs to the preprogrammed address is indicated by the output being low.

The HD74HC679 features and enable input ($\overline{G}$). When $\overline{G}$ is low, the device is enabled. When $\overline{G}$ is high, the device is disabled and the output is high regardless of the A and P inputs.

Features

- High Speed Operation: t_{pd} (A to Y) = 18 ns typ (C_L = 50 pF)
- High Output Current: Fanout of 10 LSTTL Loads
- Wide Operating Voltage: V_{CC} = 2 to 6 V
- Low Input Current: 1 µA max
- Low Quiescent Supply Current: I_{CC} (static) = 4 µA max (Ta = 25°C)
- Ordering Information

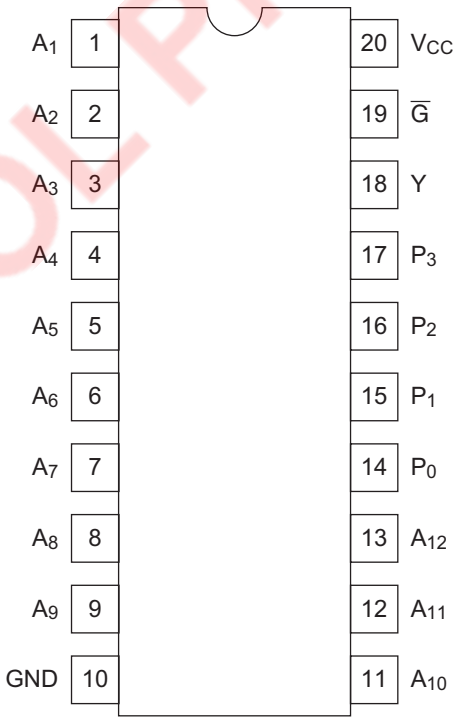
Part Name	Package Type	Package Code (Previous Code)	Package Abbreviation	Taping Abbreviation (Quantity)
HD74HC679RPEL	SOP-20 pin (JEDEC)	PRSP0020DC-A (FP-20DBV)	RP	EL (1,000 pcs/reel)

Function Table

$\overline{G}$	Inputs																Output Y
	P_3	P_2	P_1	P_0	A_1	A_2	A_3	A_4	A_5	A_6	A_7	A_8	A_9	A_{10}	A_{11}	A_{12}	
L	L	L	L	L	H	H	H	H	H	H	H	H	H	H	H	H	L
L	L	L	L	H	L	H	H	H	H	H	H	H	H	H	H	H	L
L	L	L	H	L	L	L	H	H	H	H	H	H	H	H	H	H	L
L	L	L	H	H	L	L	L	H	H	H	H	H	H	H	H	H	L
L	L	H	L	L	L	L	L	L	H	H	H	H	H	H	H	H	L
L	L	H	L	H	L	L	L	L	L	H	H	H	H	H	H	H	L
L	L	H	H	L	L	L	L	L	L	L	H	H	H	H	H	H	L
L	L	H	H	H	L	L	L	L	L	L	L	H	H	H	H	H	L
L	H	L	L	L	L	L	L	L	L	L	L	L	H	H	H	H	L
L	H	L	L	H	L	L	L	L	L	L	L	L	L	H	H	H	L
L	H	L	H	L	L	L	L	L	L	L	L	L	L	L	H	H	L
L	H	L	H	H	L	L	L	L	L	L	L	L	L	L	L	H	L
L	H	H	L	L	L	L	L	L	L	L	L	L	L	L	L	L	L
L	H	H	L	H	X	X	X	X	X	X	X	X	X	X	X	X	H
L	H	H	H	L	X	X	X	X	X	X	X	X	X	X	X	X	H
L	H	H	H	H	L	L	L	L	L	L	L	L	L	L	L	L	L
L	All other combinations																H
H	Any combination																H

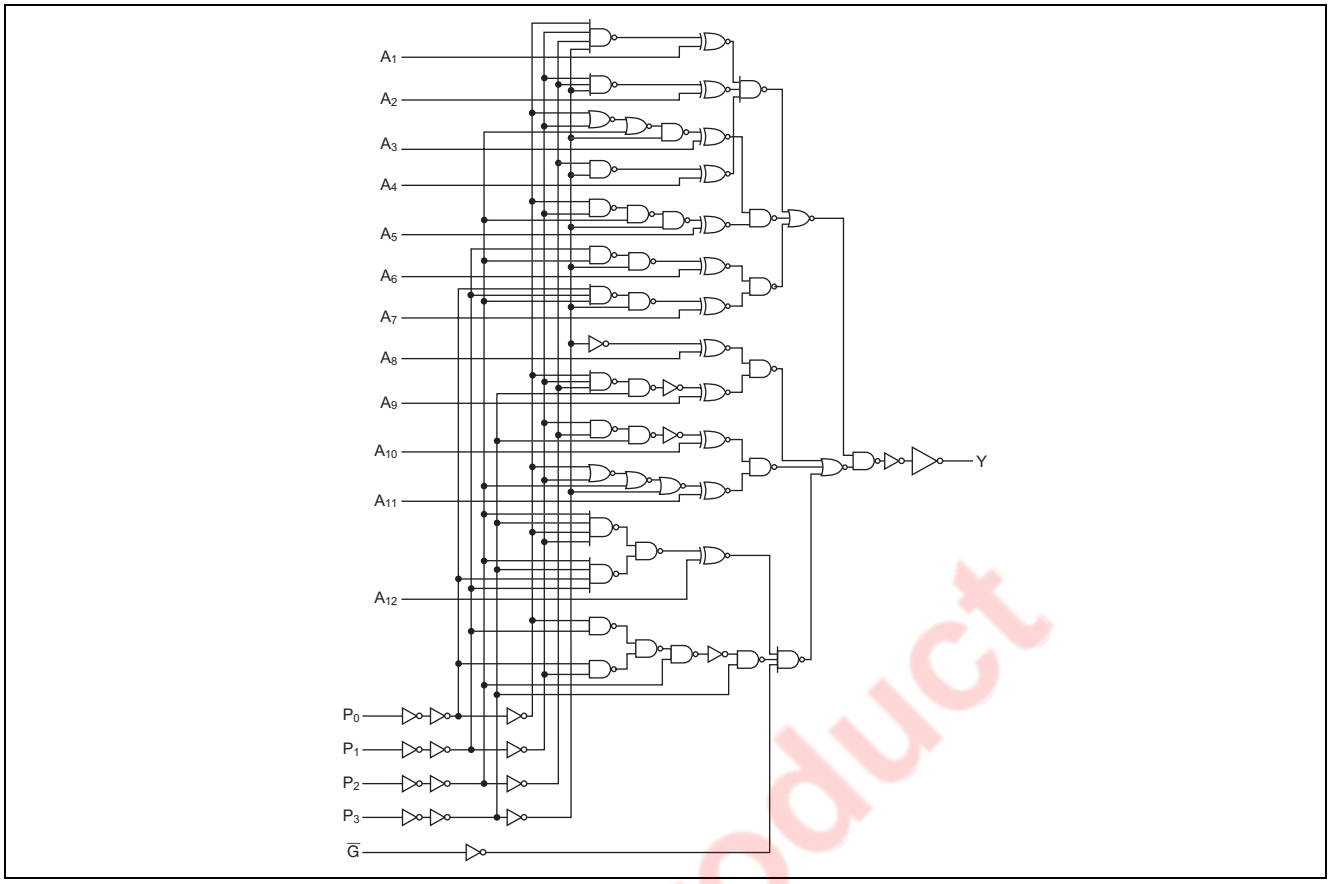
H : high level
L : low level
X : irrelevant

Pin Arrangement



(Top view)

Logic Diagram



Absolute Maximum Ratings

Item	Symbol	Ratings	Unit
Supply voltage range	V_{CC}	–0.5 to 7.0	V
Input / Output voltage	V_{IN}, V_{OUT}	–0.5 to V_{CC} +0.5	V
Input / Output diode current	I_{IK}, I_{OK}	±20	mA
Output current	I_{OUT}	±25	mA
V_{CC}, GND current	I_{CC} or I_{GND}	±50	mA
Power dissipation	P_T	500	mW
Storage temperature	Tstg	–65 to +150	°C

Note: The absolute maximum ratings are values, which must not individually be exceeded, and furthermore, no two of which may be realized at the same time.

Recommended Operating Conditions

Item	Symbol	Ratings	Unit	Conditions
Supply voltage	V_{CC}	2 to 6	V	
Input / Output voltage	V_{IN}, V_{OUT}	0 to V_{CC}	V	
Operating temperature	Ta	–40 to 85	°C	
Input rise / fall time*1	t_r, t_f	0 to 1000	ns	V_{CC} = 2.0 V
		0 to 500		V_{CC} = 4.5 V
		0 to 400		V_{CC} = 6.0 V

Note: 1. This item guarantees maximum limit when one input switches.
Waveform: Refer to test circuit of switching characteristics.

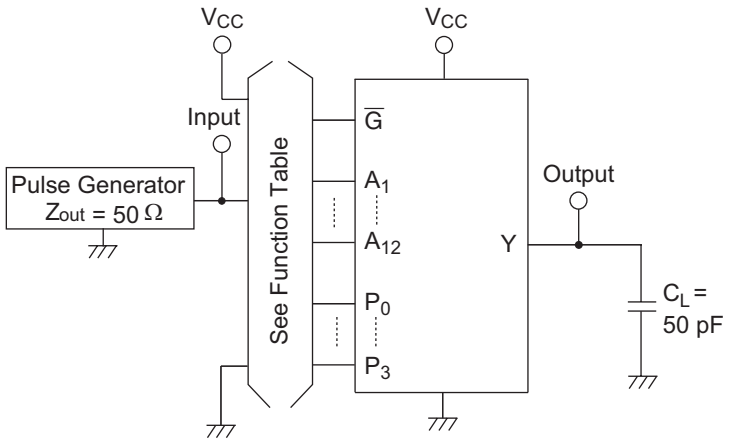
Electrical Characteristics

Item	Symbol	V_{CC} (V)	Ta = 25°C			Ta = –40 to+85°C		Unit	Test Conditions	
			Min	Typ	Max	Min	Max			
Input voltage	V_{IH}	2.0	1.5	—	—	1.5	—	V		
		4.5	3.15	—	—	3.15	—			
		6.0	4.2	—	—	4.2	—			
	V_{IL}	2.0	—	—	0.5	—	0.5	V		
		4.5	—	—	1.35	—	1.35			
		6.0	—	—	1.8	—	1.8			
Output voltage	V_{OH}	2.0	1.9	2.0	—	1.9	—	V	Vin = V_{IH} or V_{IL}	I_{OH} = –20 µA
		4.5	4.4	4.5	—	4.4	—			
		6.0	5.9	6.0	—	5.9	—			
		4.5	4.18	—	—	4.13	—			I_{OH} = –4 mA
		6.0	5.68	—	—	5.63	—			I_{OH} = –5.2 mA
	V_{OL}	2.0	—	0.0	0.1	—	0.1	V	Vin = V_{IH} or V_{IL}	I_{OL} = 20 µA
		4.5	—	0.0	0.1	—	0.1			
		6.0	—	0.0	0.1	—	0.1			
		4.5	—	—	0.26	—	0.33			I_{OL} = 4 mA
		6.0	—	—	0.26	—	0.33			I_{OL} = 5.2 mA
Input current	Iin	6.0	—	—	±0.1	—	±1.0	µA	Vin = V_{CC} or GND	
Quiescent supply current	I_{CC}	6.0	—	—	4.0	—	40	µA	Vin = V_{CC} or GND, Iout = 0 µA	

Switching Characteristics (C_L = 50 pF, Input t_r = t_f = 6 ns)

Item	Symbol	V_{CC} (V)	Ta = 25°C			Ta = –40 to +85°C		Unit	Test Conditions
			Min	Typ	Max	Min	Max		
Propagation delay time	t_{PLH} t_{PHL}	2.0	—	—	310	—	390	ns	P to Y
		4.5	—	27	62	—	78		
		6.0	—	—	52	—	66		
	t_{PLH} t_{PHL}	2.0	—	—	180	—	225	ns	A to Y
		4.5	—	18	36	—	45		
		6.0	—	—	31	—	38		
	t_{PLH} t_{PHL}	2.0	—	—	125	—	155	ns	$\overline{G}$ to Y
		4.5	—	14	25	—	31		
		6.0	—	—	21	—	26		
Output rise/fall time	t_{TLH} t_{THL}	2.0	—	—	75	—	95	ns	
		4.5	—	5	15	—	19		
		6.0	—	—	13	—	16		
Input capacitance	Cin	—	—	5	10	—	10	pF	

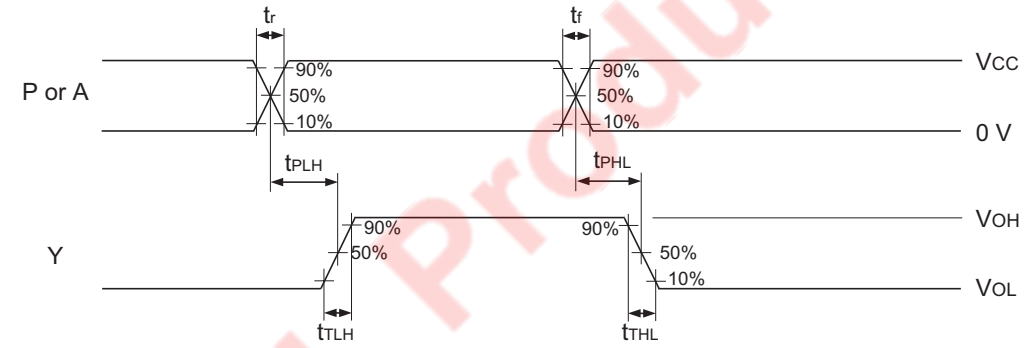
Test Circuit



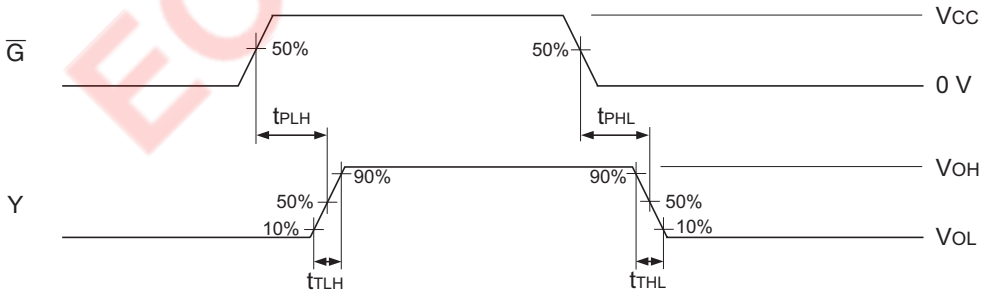
Note : 1. C_L includes probe and jig capacitance.

Waveforms

• Waveform – 1



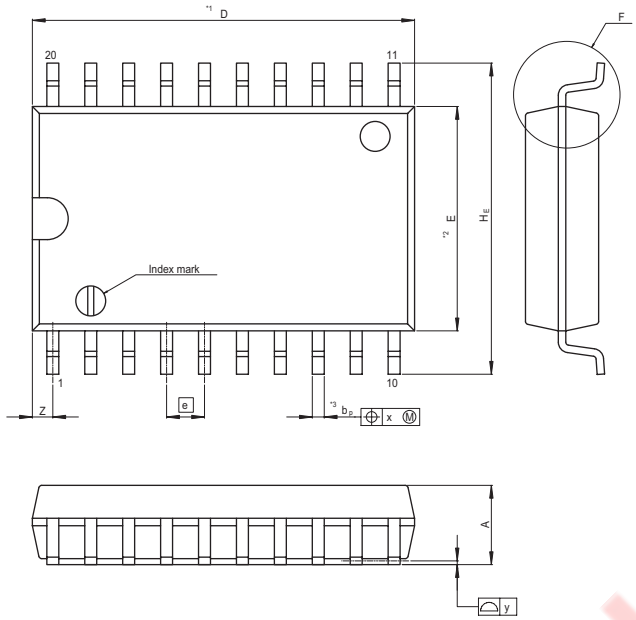
• Waveform – 2

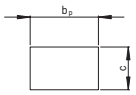


Note : 1. Input waveform : PRR ≤ 1 MHz, duty cycle 50%, $t_r \leq 6$ ns, $t_f \leq 6$ ns

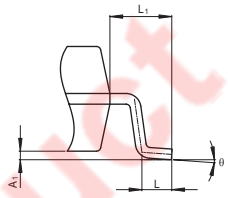
Package Dimensions

JEITA Package Code	RENESAS Code	Previous Code	MASS[Typ.]
P-SOP20-7.5x12.8-1.27	PRSP0020DC-A	FP-20DBV	0.52g





Terminal cross section
(Ni/Pd/Au plating)



Detail F

NOTE)
1. DIMENSIONS"*1 (Nom)"AND"*2"
   @ DO NOT INCLUDE MOLD FLASH.
2. DIMENSION"*3"DOES NOT
   @ INCLUDE TRIM OFFSET.

Reference Symbol	Dimension in Millimeters		
	Min	Nom	Max
D	—	12.80	13.2
E	—	7.50	—
A_2	—	—	—
A_1	0.10	0.20	0.30
A	—	—	2.65
b_p	0.34	0.40	0.46
b_1	—	—	—
c	0.20	0.25	0.30
c_1	—	—	—
θ	0°	—	8°
H_E	10.00	10.40	10.65
e	—	1.27	—
x	—	—	0.12
y	—	—	0.15
Z	—	—	0.935
L	0.40	0.70	1.27
L_1	—	1.45	—

Renesas Technology Corp. Sales Strategic Planning Div. Nippon Bldg., 2-6-2, Ohte-machi, Chiyoda-ku, Tokyo 100-0004, Japan

RENESAS SALES OFFICES

http://www.renesas.com

Refer to "**http://www.renesas.com/en/network**" for the latest and detailed information.

Renesas Technology America, Inc.
450 Holger Way, San Jose, CA 95134-1368, U.S.A
Tel: <1> (408) 382-7500, Fax: <1> (408) 382-7501

Renesas Technology Europe Limited
Dukes Meadow, Millboard Road, Bourne End, Buckinghamshire, SL8 5FH, U.K.
Tel: <44> (1628) 585-100, Fax: <44> (1628) 585-900

Renesas Technology (Shanghai) Co., Ltd.
Unit 204, 205, AZIACenter, No.1233 Lujiazui Ring Rd, Pudong District, Shanghai, China 200120
Tel: <86> (21) 5877-1818, Fax: <86> (21) 6887-7898

Renesas Technology Hong Kong Ltd.
7th Floor, North Tower, World Finance Centre, Harbour City, 1 Canton Road, Tsimshatsui, Kowloon, Hong Kong
Tel: <852> 2265-6688, Fax: <852> 2730-6071

Renesas Technology Taiwan Co., Ltd.
10th Floor, No.99, Fushing North Road, Taipei, Taiwan
Tel: <886> (2) 2715-2888, Fax: <886> (2) 2713-2999

Renesas Technology Singapore Pte. Ltd.
1 Harbour Front Avenue, #06-10, Keppel Bay Tower, Singapore 098632
Tel: <65> 6213-0200, Fax: <65> 6278-8001

Renesas Technology Korea Co., Ltd.
Kukje Center Bldg. 18th Fl., 191, 2-ka, Hangang-ro, Yongsan-ku, Seoul 140-702, Korea
Tel: <82> (2) 796-3115, Fax: <82> (2) 796-2145

Renesas Technology Malaysia Sdn. Bhd
Unit 906, Block B, Menara Amcorp, Amcorp Trade Centre, No.18, Jalan Persiaran Barat, 46050 Petaling Jaya, Selangor Darul Ehsan, Malaysia
Tel: <603> 7955-9390, Fax: <603> 7955-9510

Colophon .6.0